

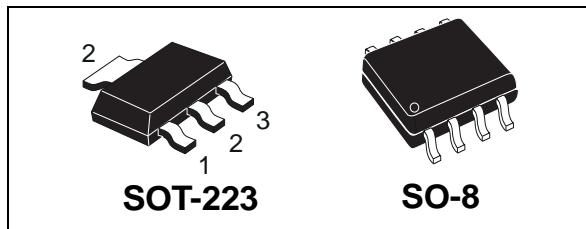


life.augmented

VNL5090N3-E VNL5090S5-E

OMNIFET III fully protected low-side driver

Datasheet - production data



Features

| Type | V_{clamp} | $R_{\text{DS(on)}}$ | I_D |
|-------------|--------------------|---------------------|-------|
| VNL5090N3-E | 41 V | 90 mΩ | 13 A |
| VNL5090S5-E | | | |

- Automotive qualified
- Drain current: 13 A
- ESD protection
- Overvoltage clamp
- Thermal shutdown
- Current and power limitation
- Very low standby current
- Very low electromagnetic susceptibility
- Compliant with European directive 2002/95/EC
- Open drain status output (Root part number 2 only)
- Specially intended for 2 x R10W or 4 x R5W automotive signal lamps

Description

The VNL5090N3-E and VNL5090S5-E are monolithic devices made using STMicroelectronics® VIPower® technology, intended for driving resistive or inductive loads with one side connected to the battery. Built-in thermal shutdown protects the chip from overtemperature and short-circuit.

Output current limitation protects the devices in an overload condition. In case of long duration overload, the device limits the dissipated power to a safe level up to thermal shutdown intervention. Thermal shutdown, with automatic restart, allows the devices to recover normal operation as soon as a fault condition disappears. Fast demagnetization of inductive loads is achieved at turn-off.

Table 1. Devices summary

| Package | Order codes | |
|---------|-------------|---------------|
| | Tube | Tape and reel |
| SOT-223 | VNL5090N3-E | VNL5090N3TR-E |
| SO-8 | VNL5090S5-E | VNL5090S5TR-E |

Contents

| | | |
|----------|---|-----------|
| 1 | Block diagrams and pins configurations | 5 |
| 2 | Electrical specifications | 8 |
| 2.1 | Absolute maximum ratings | 8 |
| 2.2 | Thermal data | 8 |
| 2.3 | Electrical characteristics | 9 |
| 3 | Application information | 13 |
| 3.1 | MCU I/O protection | 14 |
| 4 | Package and PC board thermal data | 16 |
| 4.1 | SOT-223 thermal data | 16 |
| 4.2 | SO-8 thermal data | 19 |
| 5 | Package and packing information | 22 |
| 5.1 | ECOPACK® | 22 |
| 5.2 | SOT-223 mechanical data | 22 |
| 5.3 | SO-8 mechanical data | 23 |
| 5.4 | SOT-223 packing information | 25 |
| 5.5 | SO-8 packing information | 26 |
| 6 | Revision history | 27 |

List of tables

| | | |
|-----------|--|----|
| Table 1. | Devices summary | 1 |
| Table 2. | Pin function | 6 |
| Table 3. | Suggested connections for unused and N.C. pins | 7 |
| Table 4. | Absolute maximum ratings | 8 |
| Table 5. | Thermal data..... | 8 |
| Table 6. | PowerMOS section..... | 9 |
| Table 7. | Source drain diode | 9 |
| Table 8. | Input section | 9 |
| Table 9. | Status pin | 9 |
| Table 10. | Logic input | 10 |
| Table 11. | Openload detection..... | 10 |
| Table 12. | Supply section | 10 |
| Table 13. | Switching characteristics | 11 |
| Table 14. | Protection and diagnostics | 11 |
| Table 15. | Truth table..... | 12 |
| Table 16. | SOT-223 thermal parameters..... | 18 |
| Table 17. | SO-8 thermal parameters | 21 |
| Table 18. | SOT-223 mechanical data | 23 |
| Table 19. | SO-8 mechanical data | 24 |
| Table 20. | Document revision history | 27 |

List of figures

| | | |
|------------|--|----|
| Figure 1. | VNL5090N3-E block diagram | 5 |
| Figure 2. | VNL5090S5-E block diagram | 5 |
| Figure 3. | VNL5090N3-E current and voltage conventions | 6 |
| Figure 4. | VNL5090S5-E current and voltage conventions | 6 |
| Figure 5. | Configuration diagrams (top view) | 7 |
| Figure 6. | Switching characteristics | 12 |
| Figure 7. | VNL5090N3-E application schematic | 13 |
| Figure 8. | VNL5090S5-E application schematic | 13 |
| Figure 9. | Maximum demagnetization energy ($V_{CC} = 16$ V) | 15 |
| Figure 10. | SOT-223 PC board | 16 |
| Figure 11. | SOT-223 Rthj-amb vs PCB copper area in open box free air condition | 16 |
| Figure 12. | SOT-223 thermal impedance junction ambient single pulse | 17 |
| Figure 13. | Thermal fitting model of a LSD in SOT-223 | 17 |
| Figure 14. | SO-8 PC board | 19 |
| Figure 15. | SO-8 Rthj-amb vs PCB copper area in open box free air condition | 19 |
| Figure 16. | SO-8 thermal impedance junction ambient single pulse | 20 |
| Figure 17. | Thermal fitting model of a LSD in SO-8 | 20 |
| Figure 18. | SOT-223 package dimensions | 22 |
| Figure 19. | SO-8 package dimensions | 23 |
| Figure 20. | SOT-223 tape and reel shipment (suffix "TR") | 25 |
| Figure 21. | SO-8 tube shipment (no suffix) | 26 |
| Figure 22. | SO-8 tape and reel shipment (suffix "TR") | 26 |

1 Block diagrams and pins configurations

Figure 1. VNL5090N3-E block diagram

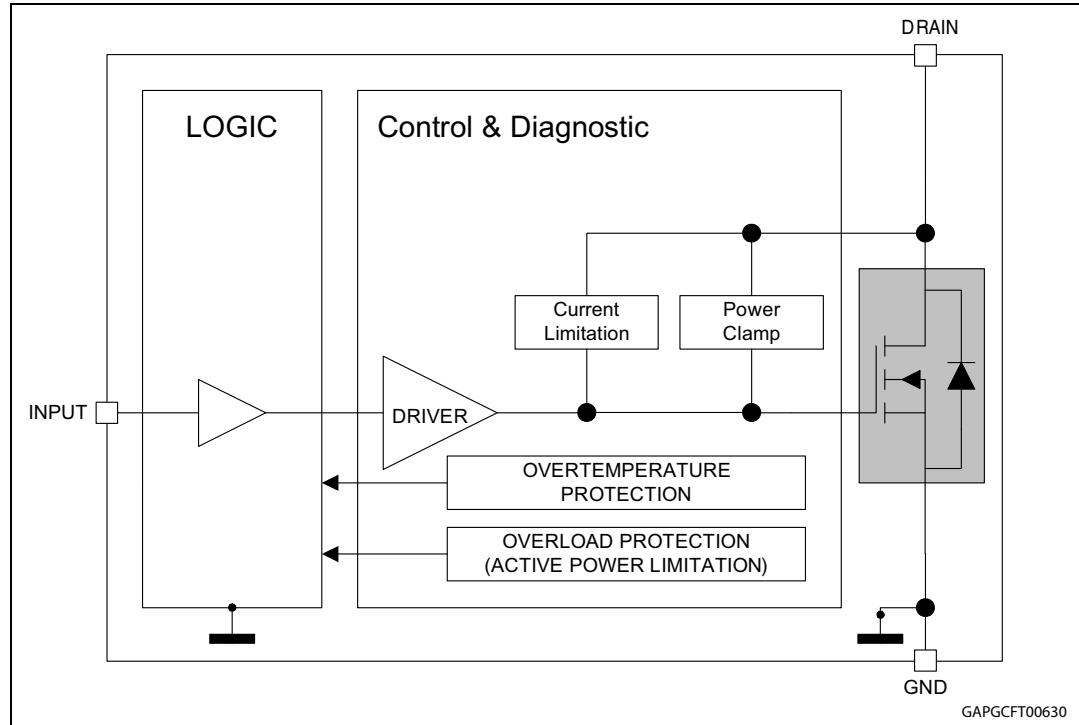


Figure 2. VNL5090S5-E block diagram

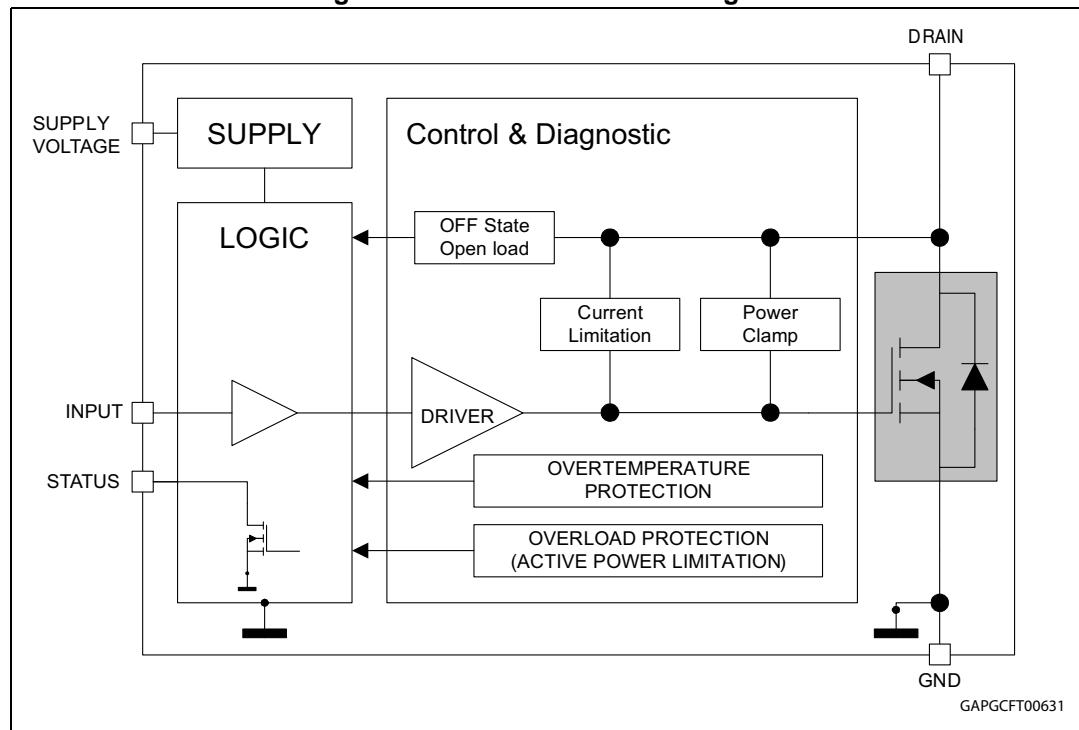


Table 2. Pin function

| Name | Function |
|----------------|---|
| INPUT | Voltage controlled input pin with hysteresis, CMOS compatible; It controls output switch state ⁽¹⁾ |
| DRAIN | PowerMOS drain |
| SOURCE | PowerMOS source and ground reference for the control section |
| SUPPLY VOLTAGE | Supply voltage connected to the signal part (5 V) |
| STATUS | Open drain digital diagnostic pin ⁽²⁾ |

1. Internally connected to V_{supply} in the VNL5090N3-E

2. Valid for VNL5090S5-E only.

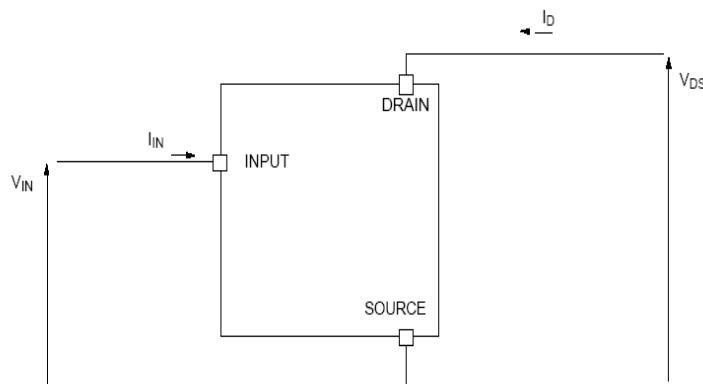
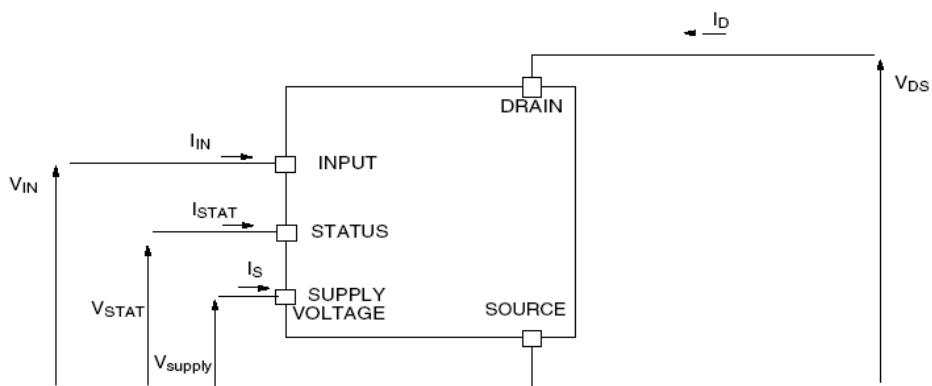
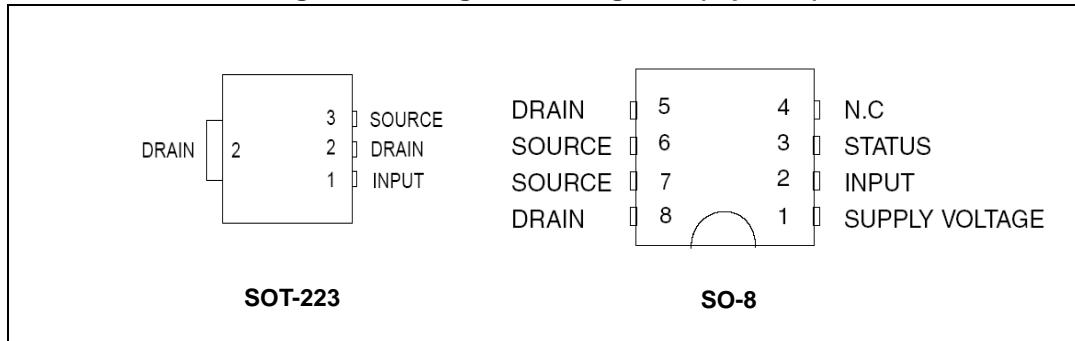
Figure 3. VNL5090N3-E current and voltage conventions**Figure 4. VNL5090S5-E current and voltage conventions**

Figure 5. Configuration diagrams (top view)**Table 3. Suggested connections for unused and N.C. pins**

| Connection / pin | Status | N.C. | Input |
|------------------|------------------|------|------------------------|
| Floating | X ⁽¹⁾ | X | X |
| To ground | Not allowed | X | Through 10 kΩ resistor |

1. X: do not care.

2 Electrical specifications

2.1 Absolute maximum ratings

Stressing the device above the rating listed in the [Table 4](#) may cause permanent damage to the device. These are stress ratings only and operation of the device at these or any other conditions above those indicated in the operating sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Table 4. Absolute maximum ratings

| Symbol | Parameter | Value | | Unit |
|------------|--|--------------------|----------|--------|
| | | SOT-223 | SO-8 | |
| V_{DS} | Drain-source voltage ($V_{IN} = 0 \text{ V}$) | Internally clamped | | V |
| I_D | DC drain current | Internally limited | | A |
| $-I_D$ | Reverse DC drain current | 12.5 | | A |
| I_S | DC supply current | — | -1 to 10 | mA |
| I_{IN} | DC input current | -1 to 10 | | mA |
| I_{STAT} | DC status current | — | -1 to 10 | mA |
| V_{ESD1} | Electrostatic discharge ($R = 1.5 \text{ k}\Omega$; $C = 100 \text{ pF}$) – DRAIN – SUPPLY, INPUT, STATUS | 5000 4000 | | V V |
| V_{ESD2} | Electrostatic discharge on output pin only ($R = 330 \Omega$, $C = 150 \text{ pF}$) | 2000 | | V |
| T_j | Junction operating temperature | -40 to 150 | | °C |
| T_{stg} | Storage temperature | -55 to 150 | | °C |
| E_{AS} | Single pulse avalanche energy ($L = 1.1 \text{ mH}$, $T_j = 150^\circ\text{C}$, $R_L = 0$, $I_{OUT} = I_{limL}$) | 50 | | mJ |

2.2 Thermal data

Table 5. Thermal data

| Symbol | Parameter | Maximum value | | Unit |
|---------------|-------------------------------------|--------------------|------|------|
| | | SOT-223 | SO-8 | |
| $R_{thj-amb}$ | Thermal resistance junction-ambient | 147 ⁽¹⁾ | 102 | °C/W |

- When mounted on a standard single-sided FR4 board with 0.5 cm^2 of Cu (at least $35 \mu\text{m}$ thick) connected to all DRAIN pins

2.3 Electrical characteristics

Values specified in this section are for $V_{\text{supply}} = V_{\text{IN}} = 4.5 \text{ V}$ to 5.5 V , $-40^{\circ}\text{C} < T_j < 150^{\circ}\text{C}$, unless otherwise stated.

Table 6. PowerMOS section

| Symbol | Parameter | Test conditions | Min. | Typ. | Max. | Unit |
|---------------------|--------------------------------------|---|------|------|------|---------------|
| V_{supply} | Operating supply voltage | | 3.5 | 5 | 5.5 | V |
| R_{ON} | ON-state resistance | $I_D = 1.6 \text{ A}; T_j = 25^{\circ}\text{C}; V_{\text{supply}} = V_{\text{IN}} = 5 \text{ V}$ | | | 90 | $\mu\Omega$ |
| | | $I_D = 1.6 \text{ A}; T_j = 150^{\circ}\text{C}; V_{\text{supply}} = V_{\text{IN}} = 5 \text{ V}$ | | | 180 | |
| | | $I_D = 1.6 \text{ A}; T_j = 150^{\circ}\text{C}; V_{\text{supply}} = V_{\text{IN}} = 4.5 \text{ V}^{(1)}$ | | | 190 | |
| V_{CLAMP} | Drain-source clamp voltage | $V_{\text{IN}} = 0 \text{ V}; I_D = 1.6 \text{ A}$ | 41 | 46 | 52 | V |
| V_{CLTH} | Drain-source clamp threshold voltage | $V_{\text{IN}} = 0 \text{ V}; I_D = 2 \text{ mA}$ | 36 | | | V |
| I_{DSS} | OFF-state output current | $V_{\text{IN}} = 0 \text{ V}; V_{\text{DS}} = 13 \text{ V}; T_j = 25^{\circ}\text{C}$ | 0 | | 3 | μA |
| | | $V_{\text{IN}} = 0 \text{ V}; V_{\text{DS}} = 13 \text{ V}; T_j = 125^{\circ}\text{C}$ | 0 | | 5 | |

1. Valid only for VNL5090N3-E.

Table 7. Source drain diode

| Symbol | Parameter | Test conditions | Min. | Typ. | Max. | Unit |
|-----------------|--------------------|--|------|------|------|------|
| V_{SD} | Forward on voltage | $I_D = 1.6 \text{ A}; V_{\text{IN}} = 0 \text{ V}$ | — | 0.8 | — | V |

Table 8. Input section⁽¹⁾

| Symbol | Parameter | Test conditions | Min. | Typ. | Max. | Unit |
|-------------------|-------------------------------|--|------|------|------|---------------|
| I_{ISS} | Supply current from input pin | ON-state: $V_{\text{supply}} = V_{\text{IN}} = 5 \text{ V}; V_{\text{DS}} = 0 \text{ V}$ | | 30 | 65 | μA |
| V_{ICL} | Input clamp voltage | $I_S = 1 \text{ mA}$ | 5.5 | | 7 | V |
| | | $I_S = -1 \text{ mA}$ | | -0.7 | | |
| V_{INTH} | Input threshold voltage | $V_{\text{DS}} = V_{\text{IN}}; I_D = 1 \text{ mA}$ | 1 | | 3.5 | V |

1. Valid for VNL5090N3-E option (input and supply pins connected together)

Table 9. Status pin⁽¹⁾

| Symbol | Parameter | Test conditions | Min. | Typ. | Max. | Unit |
|--------------------|---------------------------|---|------|------|------|---------------|
| V_{STAT} | Status low output voltage | $I_{\text{STAT}} = 1 \text{ mA}$ | | | 0.5 | V |
| I_{LSTAT} | Status leakage current | Normal operation, $V_{\text{STAT}} = 5 \text{ V}$ | | | 10 | μA |

Table 9. Status pin⁽¹⁾ (continued)

| Symbol | Parameter | Test conditions | Min. | Typ. | Max. | Unit |
|-------------------|------------------------------|--|------|------|------|------|
| C _{STAT} | Status pin input capacitance | Normal operation, V _{STAT} = 5 V | | | 100 | pF |
| V _{STCL} | Status clamp voltage | I _{STAT} = 1 mA | 5.5 | | 7 | V |
| | | I _{STAT} = -1 mA | | -0.7 | | |

1. Valid for VNL5090S5-E option

Table 10. Logic input⁽¹⁾

| Symbol | Parameter | Test conditions | Min. | Typ. | Max. | Unit |
|----------------------|--------------------------|-------------------------|------|------|------|------|
| V _{IL} | Low-level input voltage | | | | 0.9 | V |
| I _{IL} | Low-level input current | V _{IN} = 0.9 V | 1 | | | µA |
| V _{IH} | High-level input voltage | | 2.1 | | | V |
| I _{IH} | High-level input current | V _{IN} = 2.1 V | | | 10 | µA |
| V _{I(hyst)} | Input hysteresis voltage | | 0.13 | | | V |
| V _{ICL} | Input clamp voltage | I _{IN} = 1 mA | 5.5 | | 7 | V |
| | | I _{IN} = -1 mA | | -0.7 | | |

1. Valid for VNL5090S5-E option

Table 11. Openload detection⁽¹⁾

| Symbol | Parameter | Test conditions | Min. | Typ. | Max. | Unit |
|-----------------------|--|------------------------|------|------|------|------|
| V _{OI} | Openload OFF-state voltage detection threshold | V _{IN} = 0 V | 0.6 | 1.2 | 1.7 | V |
| t _{d(oloff)} | Delay between INPUT falling edge and STATUS falling edge in openload condition | I _{OUT} = 0 A | 45 | 425 | 1100 | µs |

1. Valid for VNL5090S5-E option

Table 12. Supply section⁽¹⁾

| Symbol | Parameter | Test conditions | Min. | Typ. | Max. | Unit |
|------------------|----------------------|--|------|------|------|------|
| I _S | Supply current | OFF-state; T _j = 25°C; V _{IN} = V _{DRAIN} = 0 V; | | 10 | 25 | µA |
| | | ON-state; V _{IN} = 5 V; V _{DS} = 0 V | | 25 | 65 | |
| V _{SCL} | Supply clamp voltage | I _{SCL} = 1 mA | 5.5 | | 7 | V |
| | | I _{SCL} = -1 mA | | -0.7 | | |

1. Valid for VNL5090S5-E option

Table 13. Switching characteristics⁽¹⁾

| Symbol | Parameter | Test conditions | SOT-223⁽²⁾ | | | SO-8 | | | Unit |
|---------------|-------------------------------------|---|------------------------------|-------------|-------------|-------------|-------------|-------------|-------------|
| | | | Min. | Typ. | Max. | Min. | Typ. | Max. | |
| $t_{d(ON)}$ | Turn-on delay time | $R_L = 8.2 \Omega$, $V_{CC} = 13 V^{(3)}$ | — | 8 | — | — | 8 | — | μs |
| $t_{d(OFF)}$ | Turn-off delay time | $R_L = 8.2 \Omega$, $V_{CC} = 13 V^{(3)}$ | — | 3.4 | — | — | 18 | — | μs |
| t_r | Rise time | $R_L = 8.2 \Omega$, $V_{CC} = 13 V^{(3)}$ | — | 10 | — | — | 10 | — | μs |
| t_f | Fall time | $R_L = 8.2 \Omega$, $V_{CC} = 13 V^{(3)}$ | — | 2.7 | — | — | 10 | — | μs |
| W_{ON} | Switching energy losses at turn-on | $R_L = 8.2 \Omega$, $V_{CC} = 13 V^{(3)}$ | — | 57 | — | — | 57 | — | μJ |
| W_{OFF} | Switching energy losses at turn-off | $R_L = 8.2 \Omega$, $V_{CC} = 13 V^{(3)}$ | — | 14 | — | — | 55 | — | μJ |

1. See [Figure 7: VNL5090N3-E application schematic](#) and [Figure 8: VNL5090S5-E application schematic](#)2. $3.5 V \leq V_{\text{supply}} = V_{IN} \leq 5.5 V$ 3. See [Figure 6: Switching characteristics](#)**Table 14. Protection and diagnostics**

| Symbol | Parameter | Test conditions⁽¹⁾ | Min. | Typ. | Max. | Unit |
|----------------|--|---|--------------|--------------|-------------|-------------|
| I_{limH} | DC short-circuit current | $V_{DS} = 13 V$; $V_{\text{supply}} = V_{IN} = 5 V$ | 13 | 18 | 25 | A |
| I_{limL} | Short-circuit current during thermal cycling | $V_{DS} = 13 V$; $T_R < T_j < T_{TSD}$; $V_{\text{supply}} = V_{IN} = 5 V$ | | 8 | | A |
| t_{dlimL} | Step response current limit | $V_{DS} = 13 V$; $V_{\text{input}} = 5 V$ | | 44 | | μs |
| T_{TSD} | Shutdown temperature | | 150 | 175 | 200 | °C |
| $T_R^{(2)}$ | Reset temperature | | $T_{RS} + 1$ | $T_{RS} + 5$ | | °C |
| $T_{RS}^{(3)}$ | Thermal reset of STATUS | | 135 | | | °C |
| T_{HYST} | Thermal hysteresis ($T_{TSD} - T_R$) | | | 7 | | °C |

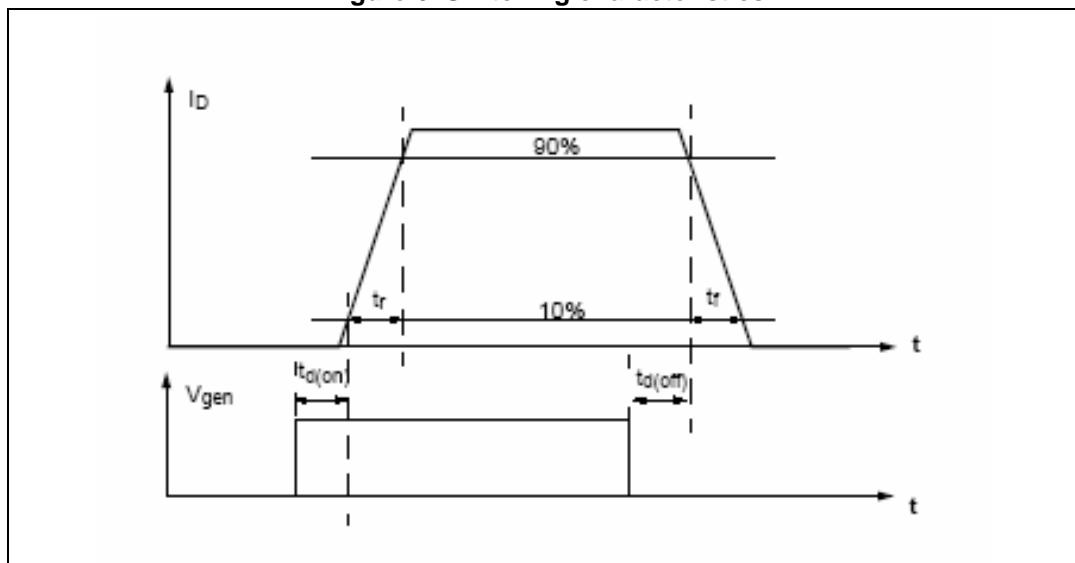
1. $V_{\text{supply}} = V_{\text{input}}$ in VNL5090N3-E version.

2. Valid for VNL5090S5-E option.

Table 15. Truth table⁽¹⁾

| Conditions | INPUT | DRAIN | STATUS |
|---------------------------|-------|-------|--------|
| Normal operation | L | H | H |
| | H | L | H |
| Current limitation | L | H | H |
| | H | X | H |
| Overtemperature | L | H | H |
| | H | H | L |
| Undervoltage | L | H | X |
| | H | H | X |
| Output voltage < V_{OL} | L | L | L |
| | H | L | H |

1. Valid for VNL5090S5-E option

Figure 6. Switching characteristics

3 Application information

Figure 7. VNL5090N3-E application schematic

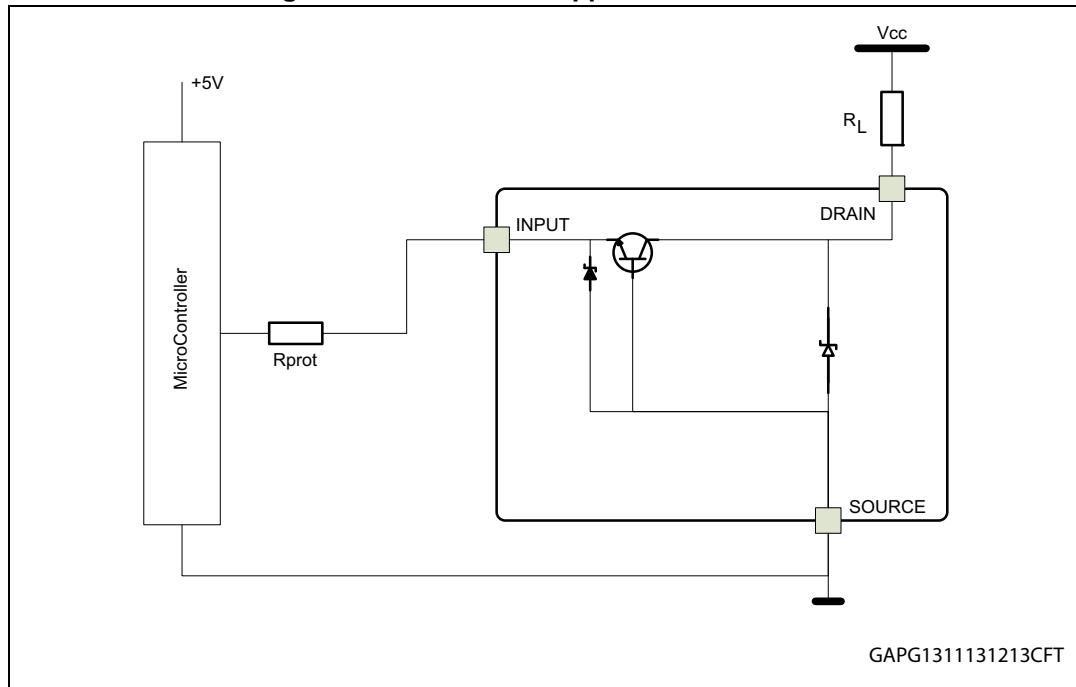
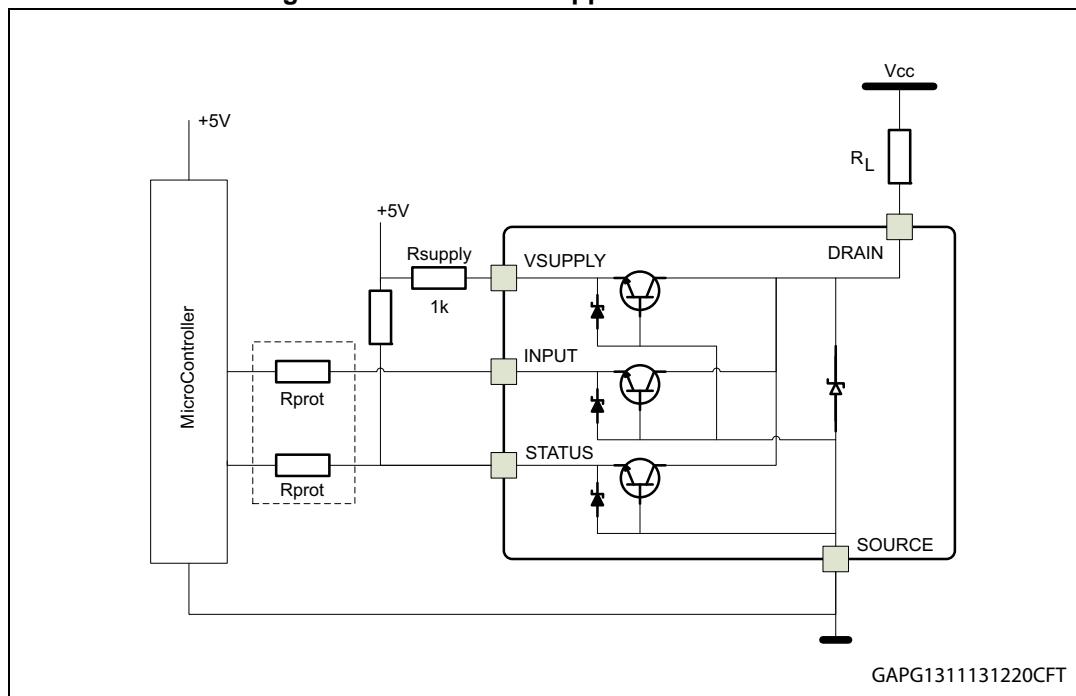


Figure 8. VNL5090S5-E application schematic



3.1 MCU I/O protection

ST suggests to insert a resistor (R_{prot}) in line to prevent the microcontroller I/O pins from latching up^(a). The value of these resistors is a compromise between the leakage current of microcontroller and the current required by the LSD I/Os (input levels compatibility) with the latch-up limit of microcontroller I/Os:

Equation 1

$$\frac{0.7}{I_{latchup}} \leq R_{prot} \leq \frac{(V_{OH\mu C} - V_{IH})}{I_{IH\ max}}$$

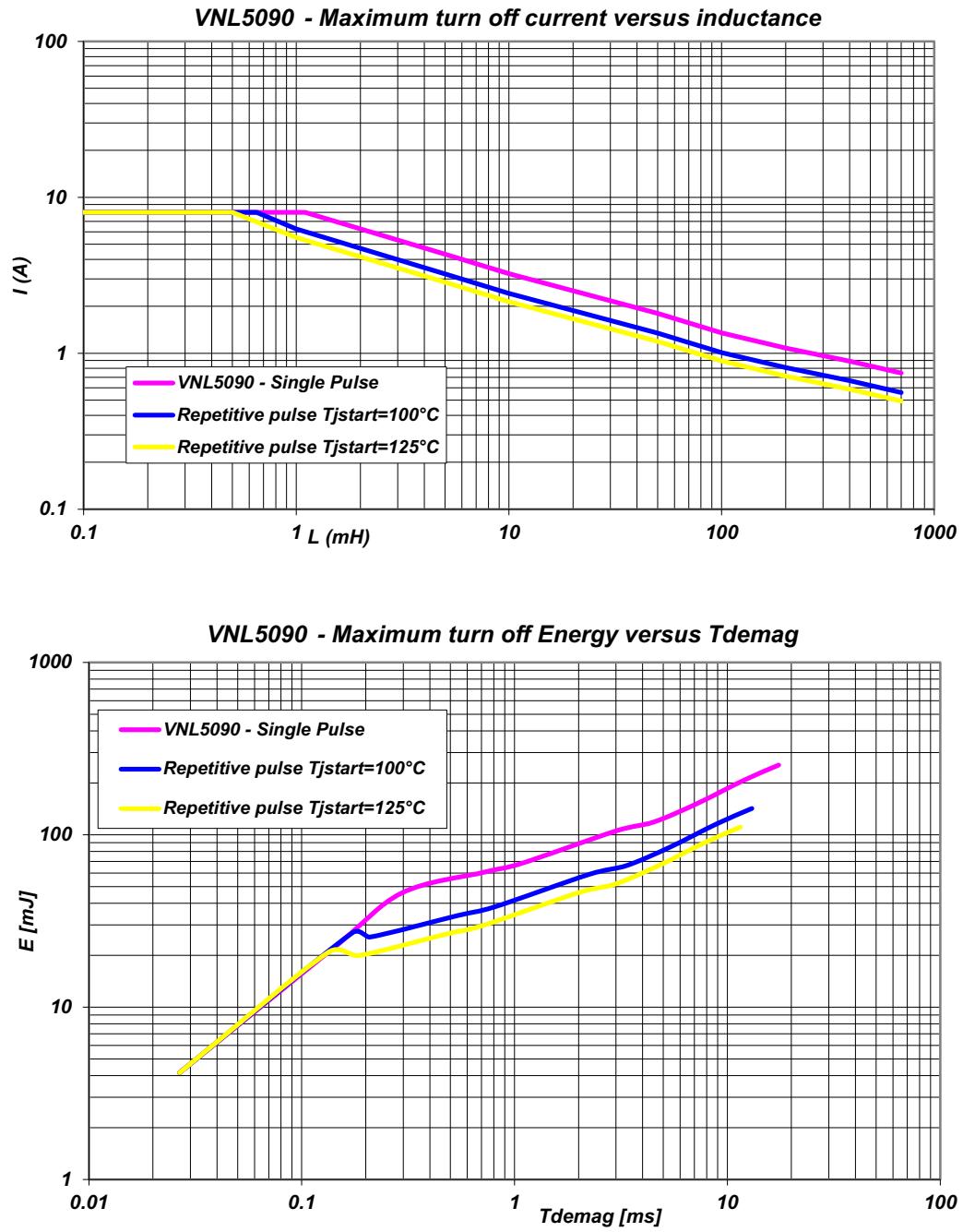
Let:

- $I_{latchup} \geq 20 \text{ mA}$
- $V_{OH\mu C} \geq 4.5 \text{ V}$
- $35 \Omega \leq R_{prot} \leq 100 \text{ k}\Omega$

Then, the recommended value is $R_{prot} = 1 \text{ k}\Omega$

Figure 9 shows the turn-off current drawn during the demagnetization.

a. In case of negative transient on the drain pin.

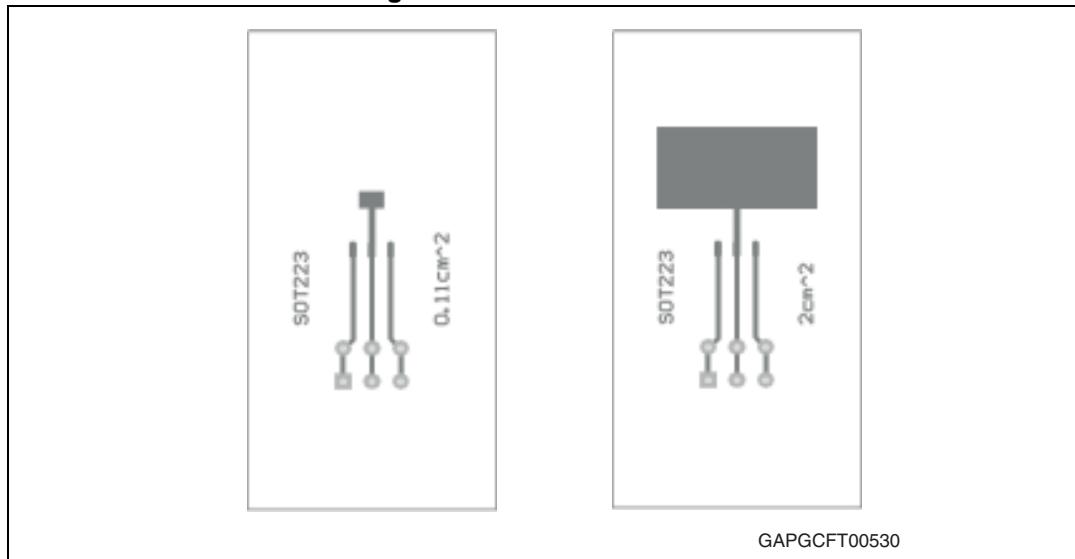
Figure 9. Maximum demagnetization energy ($V_{CC} = 16$ V)

1. The voltage supply is $V_{CC} = 13.5$ V.

4 Package and PC board thermal data

4.1 SOT-223 thermal data

Figure 10. SOT-223 PC board



Note: Layout condition of R_{th} and Z_{th} measurements (PCB FR4 area = 30 mm x 58 mm, PCB thickness = 2 mm, Cu thickness = 35 μ m, copper areas: from minimum pad lay-out to 0.8 cm^2).

Figure 11. SOT-223 $R_{thj\text{-amb}}$ vs PCB copper area in open box free air condition

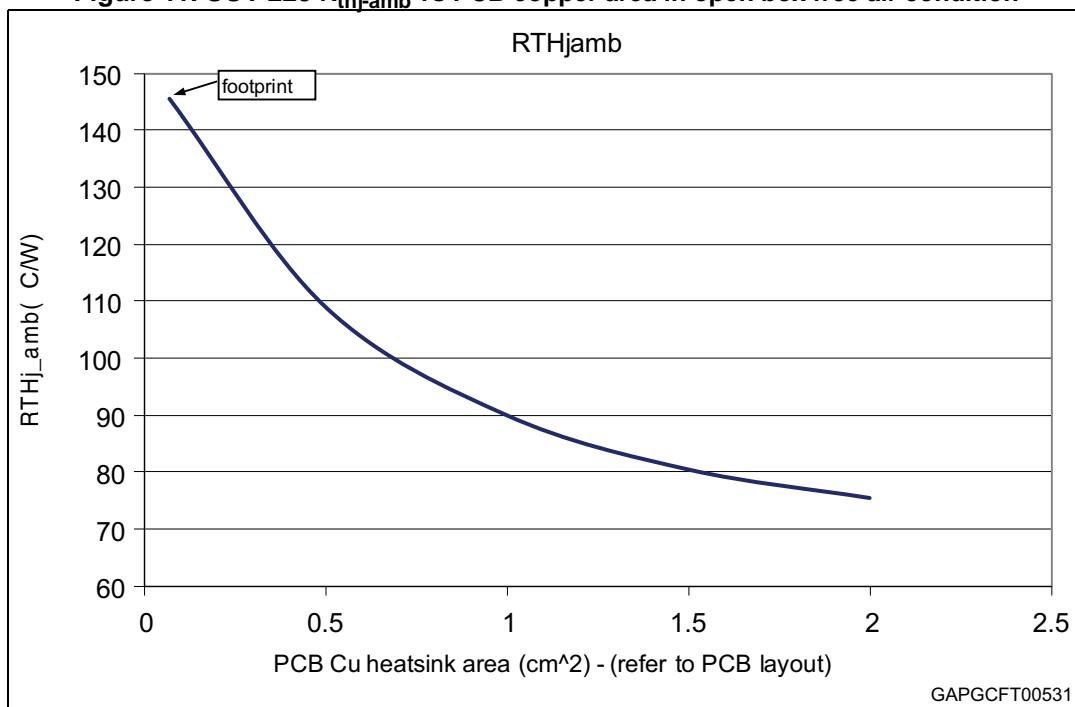
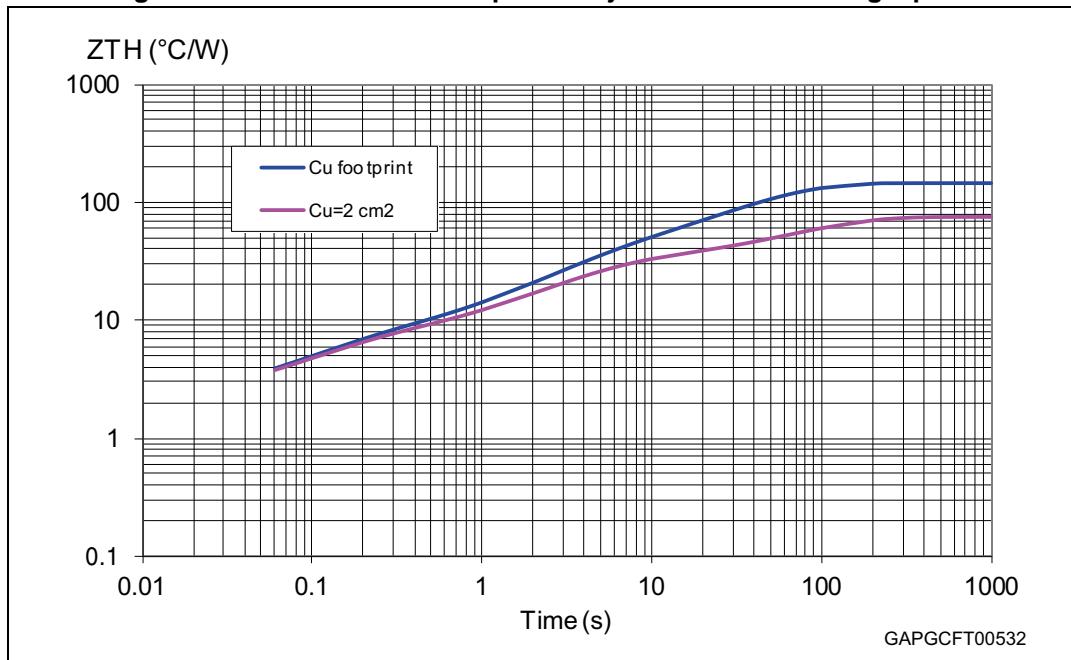
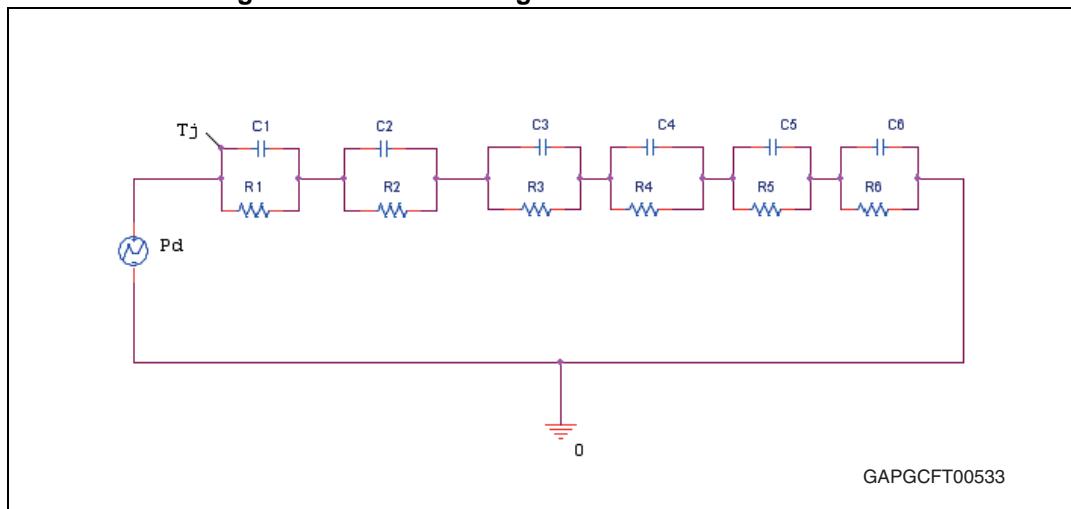


Figure 12. SOT-223 thermal impedance junction ambient single pulse**Equation 2: pulse calculation formula**

$$Z_{\text{TH}\delta} = R_{\text{TH}} \cdot \delta + Z_{\text{THtp}}(1 - \delta)$$

where $\delta = t_p/T$

Figure 13. Thermal fitting model of a LSD in SOT-223

Note:

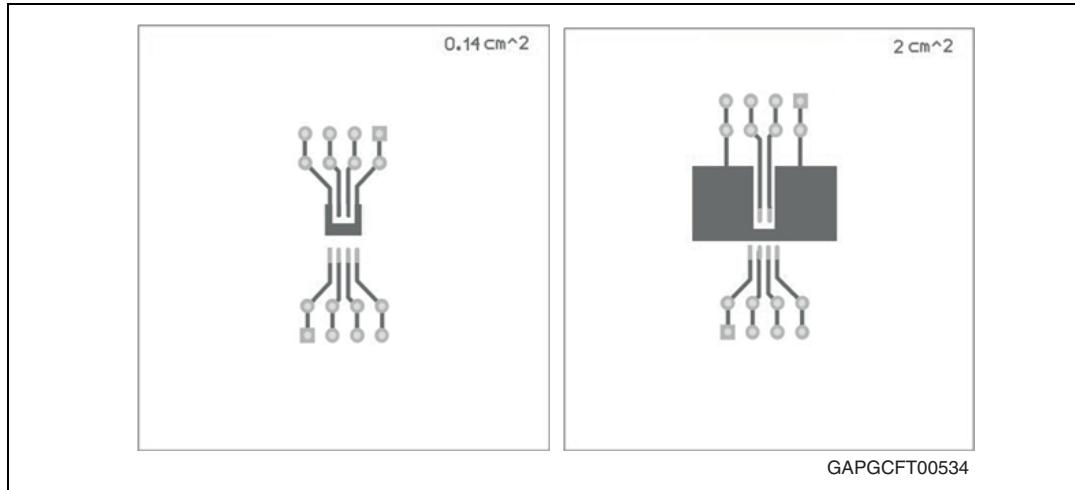
The fitting model is a simplified thermal tool and is valid for transient evolutions where the embedded protections (power limitation or thermal cycling during thermal shutdown) are not triggered.

Table 16. SOT-223 thermal parameters

| Area/island (cm ²) | Footprint | 2 |
|--------------------------------|-----------|----|
| R1 (°C/W) | 0.8 | |
| R2 (°C/W) | 1 | |
| R3 (°C/W) | 4.5 | |
| R4 (°C/W) | 24 | |
| R5 (°C/W) | 0.1 | |
| R6 (°C/W) | 115 | 45 |
| C1 (W.s/°C) | 0.00004 | |
| C2 (W.s/°C) | 0.0003 | |
| C3 (W.s/°C) | 0.03 | |
| C4 (W.s/°C) | 0.16 | |
| C5 (W.s/°C) | 1000 | |
| C6 (W.s/°C) | 0.4 | 2 |

4.2 SO-8 thermal data

Figure 14. SO-8 PC board



Note: Layout condition of R_{th} and Z_{th} measurements (PCB FR4 area = 58 mm x 58 mm, PCB thickness = 2 mm, Cu thickness = 35 μm (front and back side), Copper areas: from minimum pad lay-out to 2 cm^2).

Figure 15. SO-8 $R_{thj\text{-amb}}$ vs PCB copper area in open box free air condition

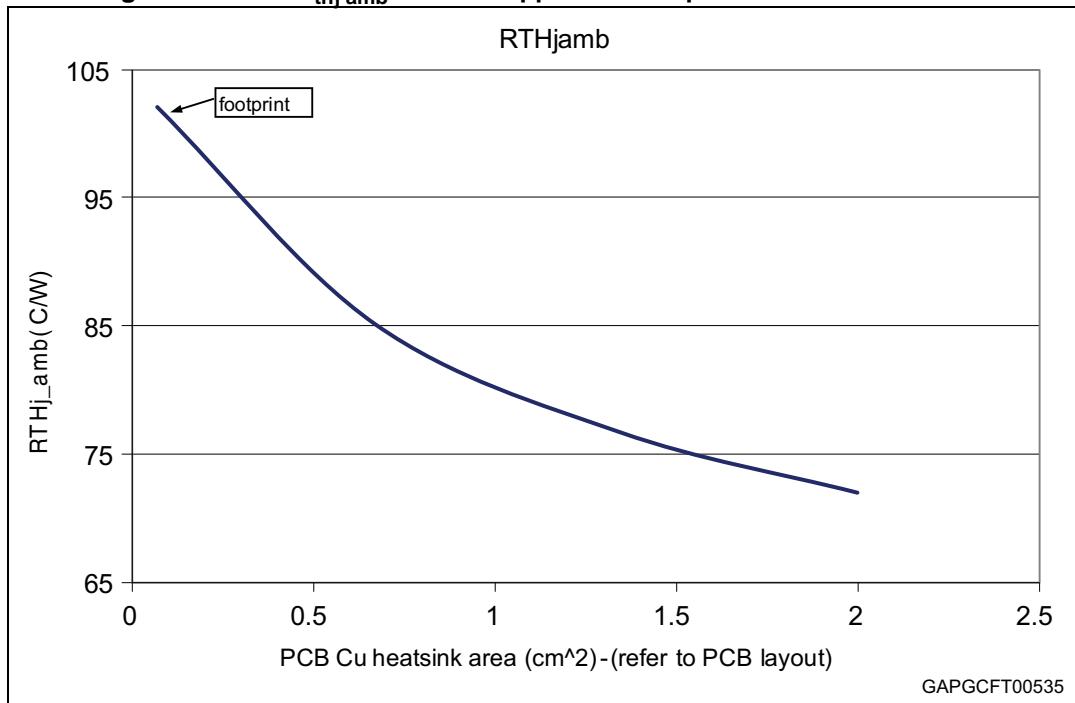
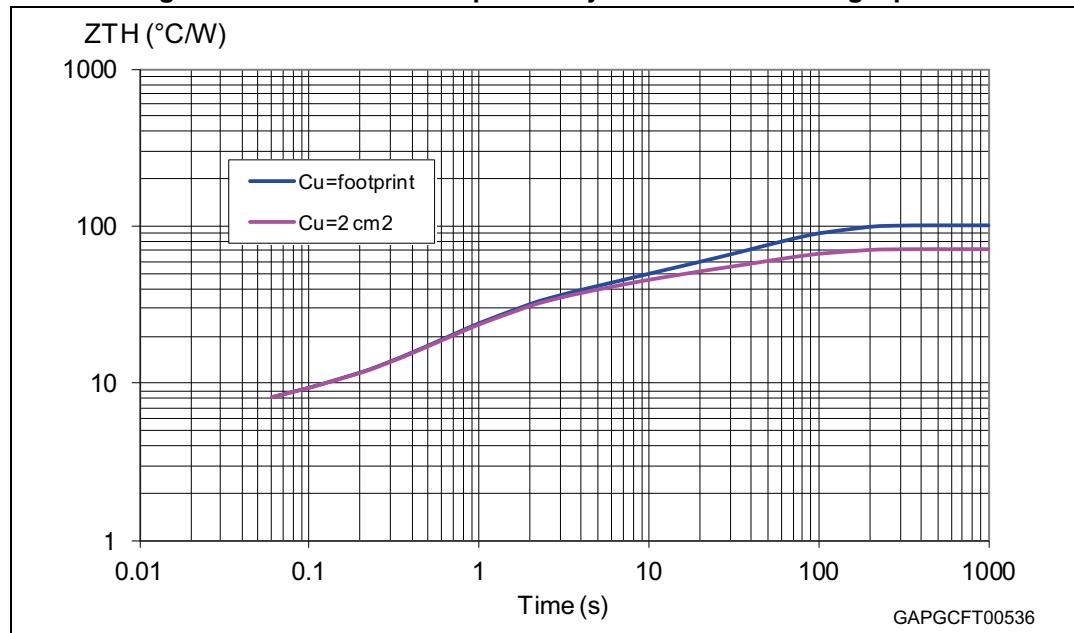
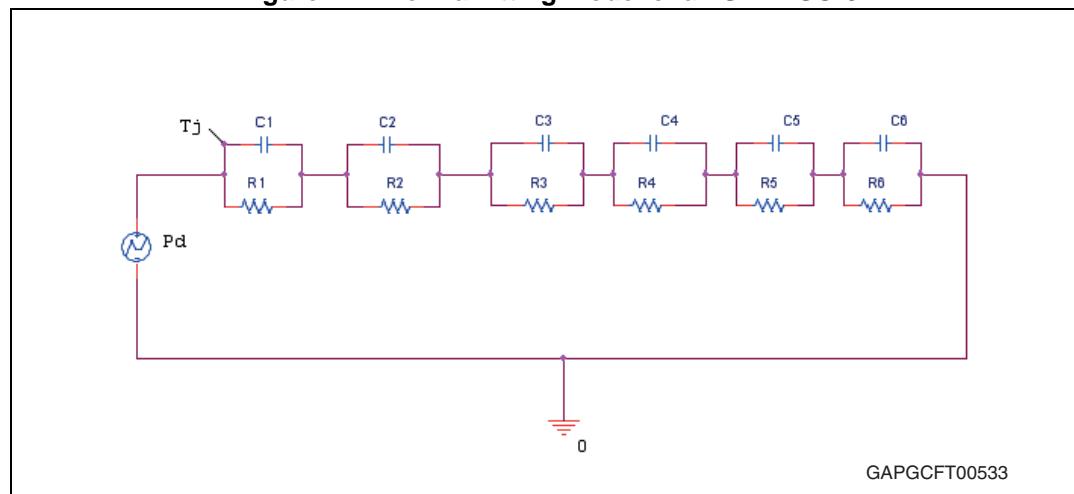


Figure 16. SO-8 thermal impedance junction ambient single pulse**Equation 3: pulse calculation formula**

$$Z_{TH\delta} = R_{TH} \cdot \delta + Z_{THtp}(1 - \delta)$$

where $\delta = t_p/T$

Figure 17. Thermal fitting model of a LSD in SO-8

Note:

The fitting model is a simplified thermal tool and is valid for transient evolutions where the embedded protections (power limitation or thermal cycling during thermal shutdown) are not triggered.

Table 17. SO-8 thermal parameters

| Area/island (cm ²) | Footprint | 2 |
|--------------------------------|-----------|----|
| R1 (°C/W) | 0.8 | |
| R2 (°C/W) | 2.7 | |
| R3 (°C/W) | 3.5 | |
| R4 (°C/W) | 21 | |
| R5 (°C/W) | 16 | |
| R6 (°C/W) | 58 | 28 |
| C1 (W.s/°C) | 0.00005 | |
| C2 (W.s/°C) | 0.001 | |
| C3 (W.s/°C) | 0.0075 | |
| C4 (W.s/°C) | 0.045 | |
| C5 (W.s/°C) | 0.35 | |
| C6 (W.s/°C) | 1.05 | 2 |

5 Package and packing information

5.1 ECOPACK®

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com.
ECOPACK® is an ST trademark.

5.2 SOT-223 mechanical data

Figure 18. SOT-223 package dimensions

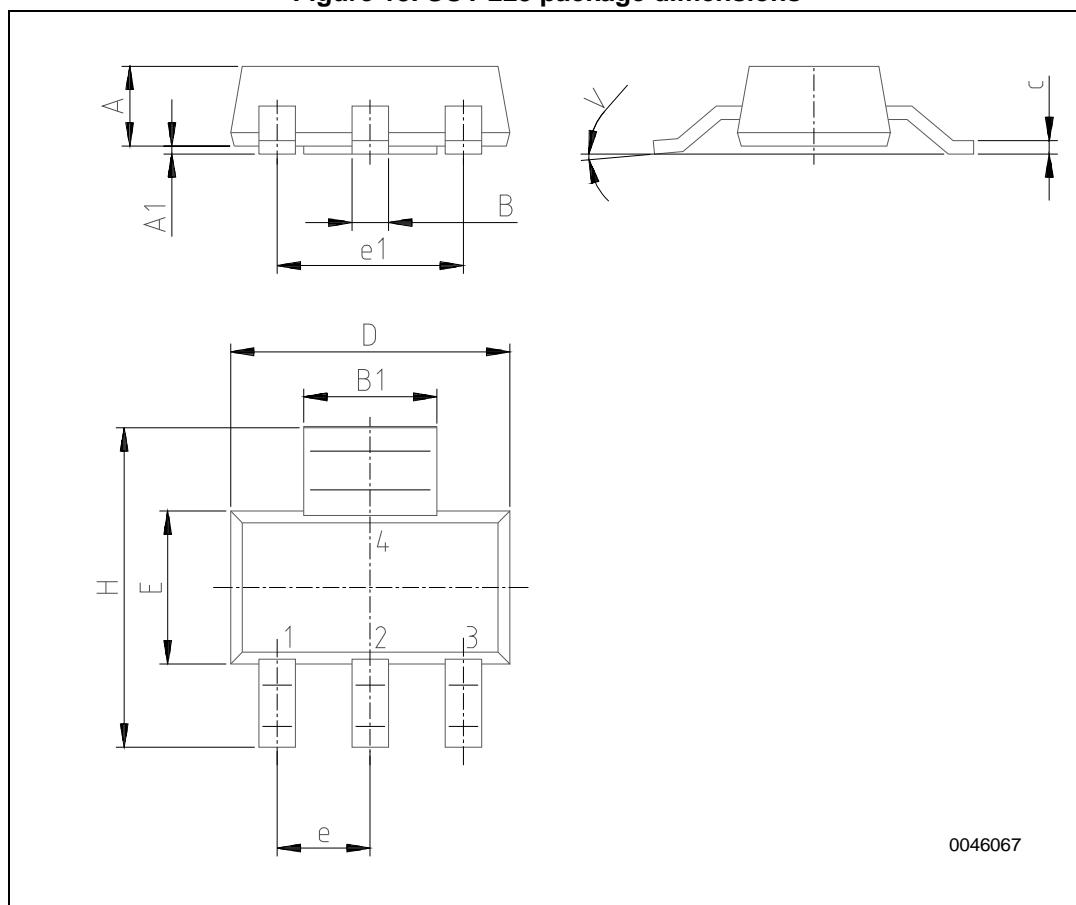


Table 18. SOT-223 mechanical data

| DIM. | mm. | | | inch | | |
|------|----------|------|------|--------|-------|-------|
| | Min. | Typ. | Max. | Min. | Typ. | Max. |
| A | | | 1.8 | | | 0.071 |
| B | 0.6 | 0.7 | 0.85 | 0.024 | 0.027 | 0.033 |
| B1 | 2.9 | 3 | 3.15 | 0.114 | 0.118 | 0.124 |
| c | 0.24 | 0.26 | 0.35 | 0.009 | 0.01 | 0.014 |
| D | 6.3 | 6.5 | 6.7 | 0.248 | 0.256 | 0.264 |
| e | | 2.3 | | | 0.09 | |
| e1 | | 4.6 | | | 0.181 | |
| E | 3.3 | 3.5 | 3.7 | 0.13 | 0.138 | 0.146 |
| H | 6.7 | 7 | 7.3 | 0.264 | 0.276 | 0.287 |
| V | 10 (max) | | | | | |
| A1 | 0.02 | | 0.1 | 0.0008 | | 0.004 |

5.3 SO-8 mechanical data

Figure 19. SO-8 package dimensions

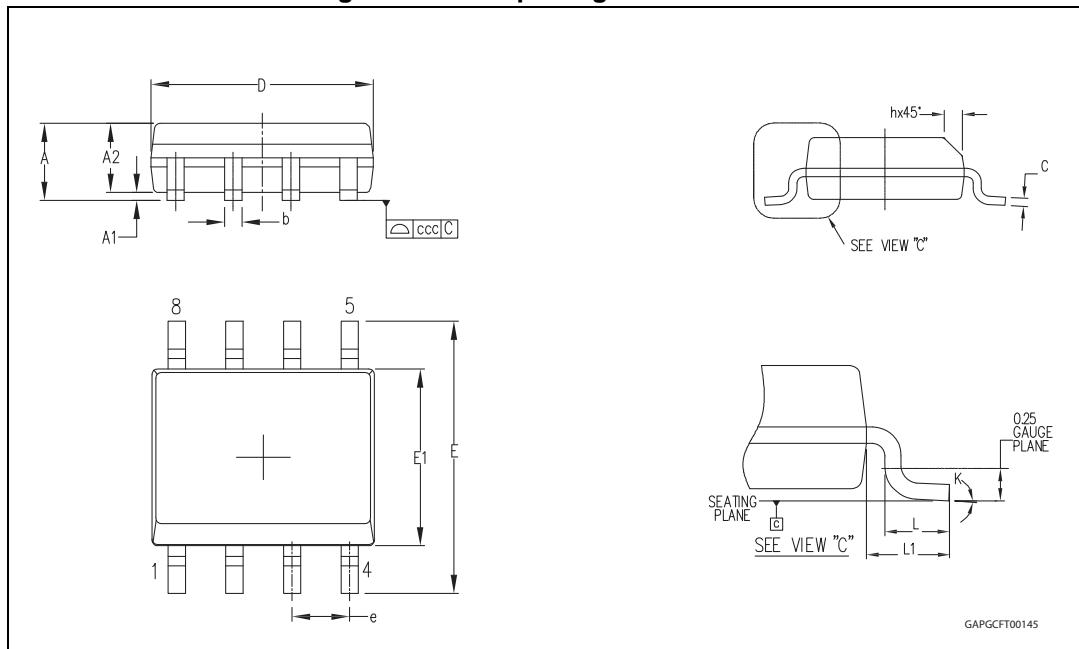


Table 19. SO-8 mechanical data

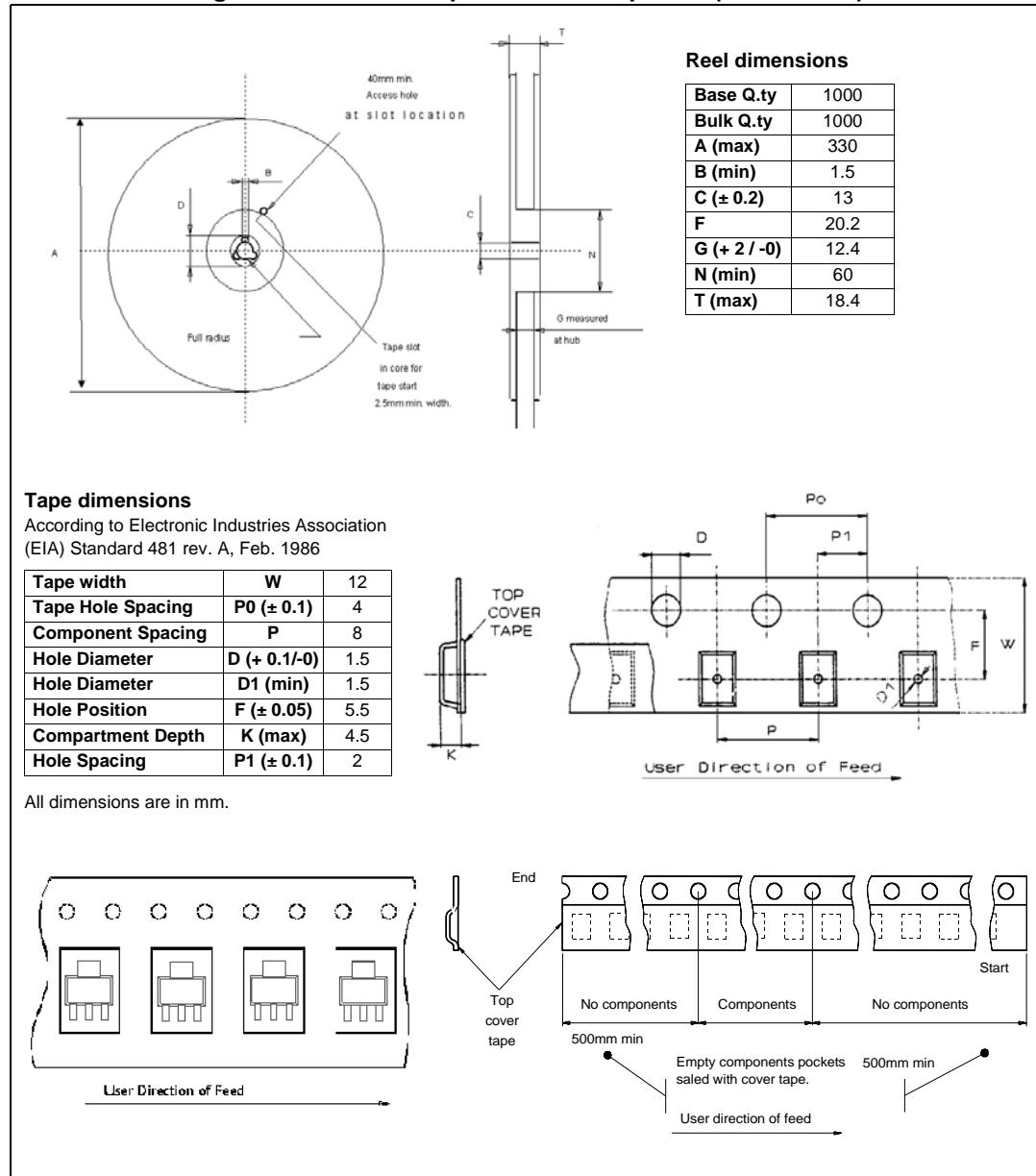
| Symbol | Millimeters | | |
|-------------------|-------------|------|------|
| | Min. | Typ. | Max. |
| A | | | 1.75 |
| A1 | 0.10 | | 0.25 |
| A2 | 1.25 | | |
| b | 0.28 | | 0.48 |
| c | 0.17 | | 0.23 |
| D ⁽¹⁾ | 4.80 | 4.90 | 5.00 |
| E | 5.80 | 6.00 | 6.20 |
| E1 ⁽²⁾ | 3.80 | 3.90 | 4.00 |
| e | | 1.27 | |
| h | 0.25 | | 0.50 |
| L | 0.40 | | 1.27 |
| L1 | | 1.04 | |
| k | 0° | | 8° |
| ccc | | | 0.10 |

- Dimensions D does not include mold flash, protrusions or gate burrs. Mold flash, potrusions or gate burrs shall not exceed 0.15 mm in total (both side).
- Dimension "E1" does not include interlead flash or protrusions. Interlead flash or protrusions shall not exceed 0.25 mm per side.

5.4 SOT-223 packing information

The devices can be packed in tube or tape and reel shipments (see the [Table 1: Devices summary on page 1](#)).

Figure 20. SOT-223 tape and reel shipment (suffix “TR”)



5.5 SO-8 packing information

Figure 21. SO-8 tube shipment (no suffix)

Dimensions:

| | |
|---|------|
| Base q.ty | 100 |
| Bulk q.ty | 2000 |
| Tube length (± 0.5) | 532 |
| A | 3.2 |
| B | 6 |
| C (± 0.1) | 0.6 |

All dimensions are in mm.

Figure 22. SO-8 tape and reel shipment (suffix "TR")

Reel dimensions:

| | |
|---------------------------------|------|
| Base q.ty | 2500 |
| Bulk q.ty | 2500 |
| A (max) | 330 |
| B (min) | 1.5 |
| C (± 0.2) | 13 |
| F | 20.2 |
| G ($+2/-0$) | 12.4 |
| N (min) | 60 |
| T (max) | 18.4 |

All dimensions are in mm.

Tape dimensions:
According to Electronic Industries Association (EIA) Standard 481 rev. A, Feb. 1986

| | | |
|--------------------------|----------------------------------|-----|
| Tape width | W | 12 |
| Tape hole spacing | P0 (± 0.1) | 4 |
| Component spacing | P | 8 |
| Hole diameter | D ($+0.1/-0$) | 1.5 |
| Hole diameter | D1 (min) | 1.5 |
| Hole position | F (± 0.05) | 5.5 |
| Compartment depth | K (max) | 4.5 |
| Hole spacing | P1 (± 0.1) | 2 |

All dimensions are in mm.

User Direction of Feed

Top cover tape:

Component layout:

Dimensions:

- End
- Top cover tape
- No components
- Components
- No components
- Empty components pockets sealed with cover tape.
- User direction of feed
- 500mm min
- 500mm min

6 Revision history

Table 20. Document revision history

| Date | Revision | Changes |
|-------------|----------|---|
| 15-Dec-2011 | 1 | Initial release. |
| 20-Jan-2012 | 2 | <i>Table 4: Absolute maximum ratings:</i> – $-I_D$: updated value |
| 18-Apr-2012 | 3 | Updated <i>Features</i> list |
| 10-Aug-2012 | 4 | Updated <i>Table 13: Switching characteristics</i> |
| 18-Sep-2013 | 5 | Updated disclaimer. |
| 13-Nov-2013 | 6 | Updated <i>Features</i> list <i>Table 8: Input section:</i> – I_{ISS} : updated maximum value <i>Table 12: Supply section:</i> – I_{IS} : updated maximum value Updated <i>Figure 7: VNL5090N3-E application schematic</i> and <i>Figure 8: VNL5090S5-E application schematic</i> Updated <i>Section 3.1: MCU I/O protection</i> |

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